

Technical Data Data Sheet N1792, Rev. A





# 245NQ400(R)-1 Ultrafast Recovery Modules



#### **Features**

- Reduced RFI and EMI
- Reduced Snubbing
- Extensive Characterization of Recovery Parameters
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request



## **Maximum Ratings:**

Characteristics	Symbol	Condition	Max.	Units
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	$egin{array}{c} V_{RRM} \ V_{RWM} \ V_{R} \end{array}$	-	400	V
Average Forward Current	I <sub>F(AV)</sub>	50% duty cycle @Tc=100°C, rectangular wave form	240	Α
Peak One Cycle Non-Repetitive Surge Current	I <sub>FSM</sub>	8.3 ms, half Sine pulse	1600	Α

## **Electrical Characteristics:**

Characteristics	Symbol	Condition	Тур.	Max.	Units
Forward Voltage Drop*	V <sub>F1</sub>	@ 135A, Pulse, TJ = 25 °C	0.968	-	V
	$V_{F2}$	@ 240A, Pulse, T <sub>J</sub> = 25 °C	1.113	1.50	V
	V <sub>F3</sub>	@ 270A, Pulse, T <sub>J</sub> = 25 °C	1.177	-	V
Reverse Current *	I <sub>R</sub>	@V <sub>R</sub> = rated VR T <sub>J</sub> = 25 °C	0.6	30	μA
Junction Capacitance	Ст	$@V_R = 5V, T_C = 25 °C$ $f_{SIG} = 1MHz$	1350	2000	pF
Reverse Recovery Time	t <sub>rr</sub>	I <sub>F</sub> =0.5A, I <sub>R</sub> =1A,and I <sub>RR</sub> =0.25A	110	150	ns
	t <sub>rr</sub>	$I_F = 1.0A$ , dif /dt = 200A/ $\mu$ s, $V_R = 30V$	96	-	ns

<sup>\*</sup> Pulse width < 300  $\mu$ s, duty cycle < 2%

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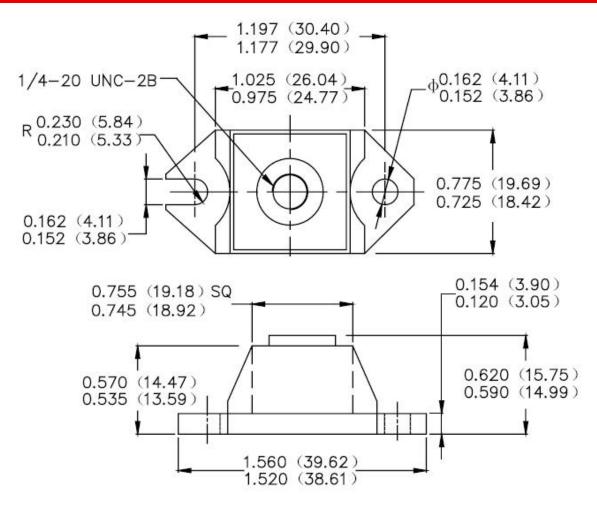




### **Thermal-Mechanical Specifications:**

Characteristics	Symbol	Condition	Specific	cation	Units
Junction Temperature	TJ	-	-55 to +150		°C
Storage Temperature	T <sub>stg</sub>	-	-55 to +150		°C
Typical Thermal Resistance Junction to Case	$R_{ heta JC}$	DC operation	0.2	:0	°C/W
Typical Thermal Resistance, case to Heat Sink	$R_{ heta cs}$	Mounting surface, smooth and greased	0.15		°C/W
Mounting Torque	т	Non-lubricated threads	Mounting Torque	23(min) 29(max)	- Kg-cm
	$T_M$		Terminal Torque	35(min) 46(max)	
Approximate Weight	wt	- 25.6		g	
Case Style	PRM1-1				

### **Mechanical Dimensions PRM1-1 (Inches/Millimeters)**



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#### **Ordering Information**

Device	Package	Shipping
245NQ400(R)-1	PRM1-1(Pb-Free)	27pcs/ box

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our tape and reel packaging specification.

#### **Marking Diagram**

SS XXXX

245NQ400-1

Where XXXX is YYWW

1st row SS YYWW
2nd row 245NQ400-1
SS = SS
YY = Year
WW = Week

Cautions: Molding resin

Epoxy resin UL:94V-0

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